SENSITRON SEMICONDUCTOR SHD126224 SHD126224P SHD126224N SHD126224D

TECHNICAL DATA DATA SHEET 775, REV. A

HERMETIC POWER SCHOTTKY RECTIFIER

Add Suffix "S" for S-100 Screening

Applications:

• Switching Power Supply • Converters • Free-Wheeling Diodes • Polarity Protection Diode

Features:

- Ultra low Reverse Leakage Current
- Soft Reverse Recovery at Low and High Temperature
- Very Low Forward Voltage Drop
- Low Power Loss, High Efficiency
- High Surge Capacity
- Guard Ring for Enhanced Durability and Long Term Reliability
- Guaranteed Reverse Avalanche Characteristics
- Out Performs 100 Volt Ultrafast Rectifiers

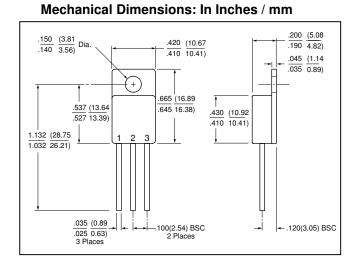
Maximum Ratings:

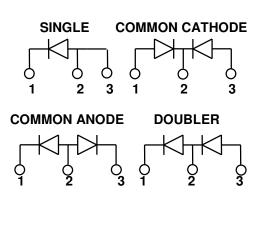
Characteristics	Symbol	Condition	Max.	Units
Peak Inverse Voltage	V _{RWM}	-	100	V
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form (Single & Doubler)	15	A
Max. Average Forward Current	I _{F(AV)}	50% duty cycle, rectangular wave form (Common Anode & Common Cathode)	30	A
Max. Peak One Cycle Non- Repetitive Surge Current	I _{FSM}	8.3 ms, half Sine wave (per leg)	100	A
Max. Thermal Resistance	R _{eJC}	(per leg)	1.9	°C/W
Max. Junction Temperature	TJ	-	-65 to +175	°C
Max. Storage Temperature	T _{stg}	_	-65 to +175	°C

Electrical Characteristics:

Characteristics	Symbol	Condition	Max.	Units
Max. Forward Voltage Drop	V_{F1}	@ 15A, Pulse, T _J = 25 °C	1.0	V
		(per leg)		
	V _{F2}	@ 15A, Pulse, T _J = 125 °C	0.9	V
		(per leg)		
Max. Reverse Current	I _{R1}	@V _R = 100V, Pulse,	0.55	mA
		T _J = 25 °C (per leg)		
	I _{R2}	@V _R = 100V, Pulse,	12.0	mA
		T _J = 125 °C (per leg)		
Max. Junction Capacitance	CT	@V _R = 5V, T _C = 25 °C	500	pF
		f _{SIG} = 1MHz,		
		$V_{SIG} = 50 \text{mV} (\text{p-p}) (\text{per leg})$		

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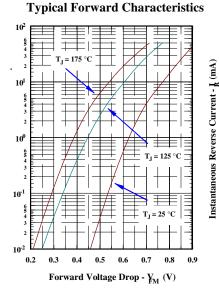




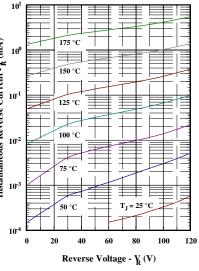
TO-257

PINOUT TABLE

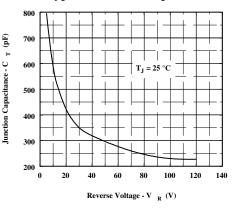
ТҮРЕ	PIN 1	PIN 2	PIN 3
SINGLE RECTIFIER	CATHODE	ANODE	ANODE
DUAL RECTIFIER, COMMON CATHODE (P)	ANODE 1	COMMON CATHODE	ANODE 2
DUAL RECTIFIER, COMMON ANODE (N)	CATHODE 1	COMMON ANODE	CATHODE 2
DUAL RECTIFIER, DOUBLER (D)	CATHODE	ANODE/CATHODE	ANODE



Typical Reverse Characteristics



Typical Junction Capacitance





TECHNICAL DATA

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